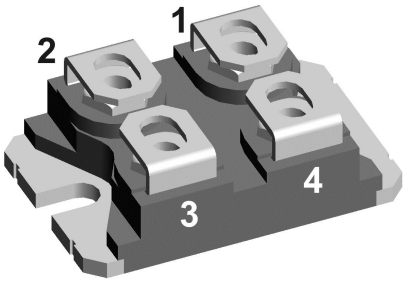
Schottky Diode

V_{RRM}	=	100 V
I_{FAV}	= 2x	40 A
V_F	=	0.7 V

High Performance Schottky Diode
Low Loss and Soft Recovery
Parallel legs

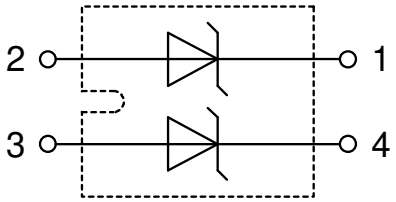
Part number

DSS2x41-01A



Backside: isolated

E72873



Features / Advantages:

- Very low Vf
- Extremely low switching losses
- Low Irm values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching

Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

Package: SOT-227B (minibloc)

- Isolation Voltage: 3000 V~
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Base plate: Copper internally DCB isolated
- Advanced power cycling

Disclaimer Notice

Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at www.littelfuse.com/disclaimer-electronics.

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Schottky				Ratings			
Symbol	**Definition**	**Conditions**		**min.**	**typ.**	**max.**	**Unit**
V_{RSM}	*max. non-repetitive reverse blocking voltage*		T_{VJ} = 25°C			100	V
V_{RRM}	*max. repetitive reverse blocking voltage*		T_{VJ} = 25°C			100	V
I_R	*reverse current, drain current*	V_R = 100 V	T_{VJ} = 25°C			1	mA
		V_R = 100 V	T_{VJ} = 125°C			10	mA
V_F	*forward voltage drop*	I_F = 40 A	T_{VJ} = 25°C			0.88	V
		I_F = 80 A				1.05	V
		I_F = 40 A	T_{VJ} = 125°C			0.70	V
		I_F = 80 A				0.88	V
I_{FAV}	*average forward current*	T_C = 110°C rectangular d = 0.5	T_{VJ} = 150°C			40	A
V_{F0}	*threshold voltage* } *for power loss calculation only*		T_{VJ} = 150°C			0.49	V
r_F	*slope resistance*					4.3	mΩ
R_{thJC}	*thermal resistance junction to case*					1.1	K/W
R_{thCH}	*thermal resistance case to heatsink*				0.1		K/W
P_{tot}	*total power dissipation*		T_C = 25°C			110	W
I_{FSM}	*max. forward surge current*	t = 10 ms; (50 Hz), sine; V_R = 0 V	T_{VJ} = 45°C			450	A
C_J	*junction capacitance*	V_R = 12 V f = 1 MHz	T_{VJ} = 25°C		572		pF

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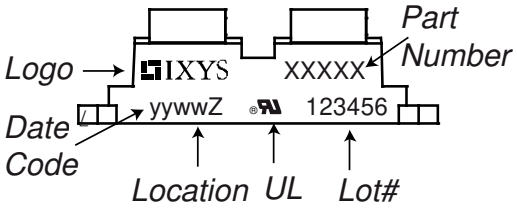
Package SOT-227B (minibloc)					Ratings			
Symbol	**Definition**	**Conditions**			**min.**	**typ.**	**max.**	**Unit**
I_{RMS}	*RMS current*	per terminal					70	A
T_{VJ}	*virtual junction temperature*				-40		150	°C
T_{op}	*operation temperature*				-40		125	°C
T_{stg}	*storage temperature*				-40		150	°C
Weight						30		g
M_D	*mounting torque*				1.1		1.5	Nm
M_T	*terminal torque*				1.1		1.5	Nm
$d_{Spp/App}$	*creepage distance on surface | striking distance through air*		*terminal to terminal*	10.5	3.2			mm
$d_{Spb/Apb}$			*terminal to backside*	8.6	6.8			mm
V_{ISOL}	*isolation voltage*	t = 1 second	50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA		3000			V
		t = 1 minute			2500			V

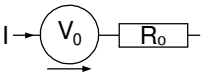
Product Marking



Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSS2x41-01A	DSS2x41-01A	Tube	10	475556

Equivalent Circuits for Simulation

** on die level* $T_{VJ} = 150°C$



Schottky

$V_{0\,max}$	*threshold voltage*	0.49	V
$R_{0\,max}$	*slope resistance **	2.5	mΩ

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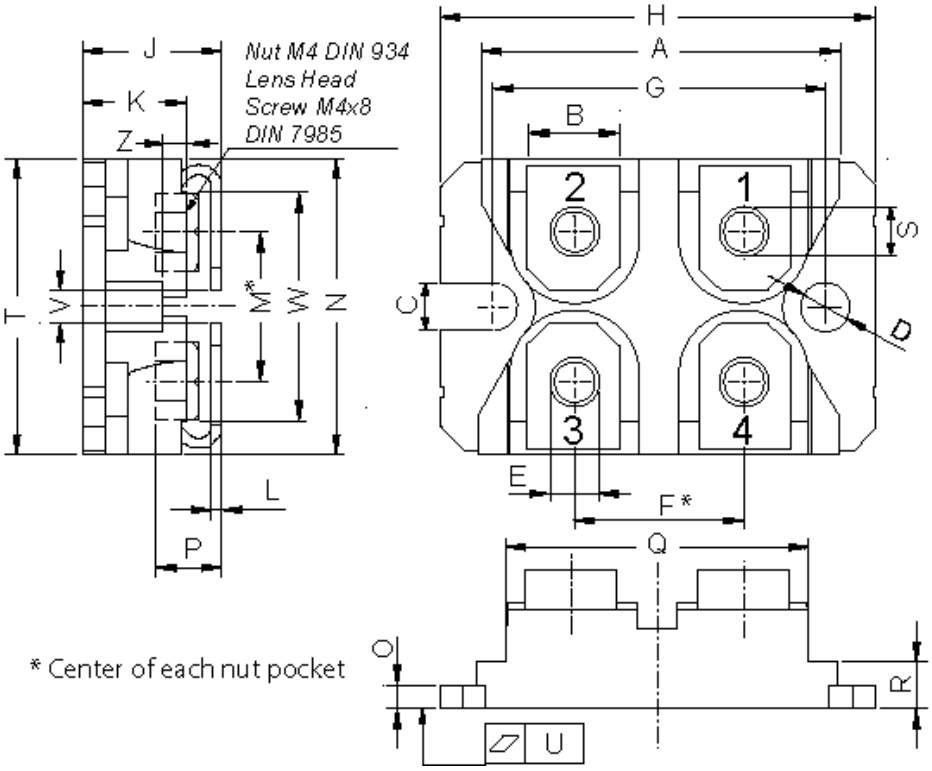
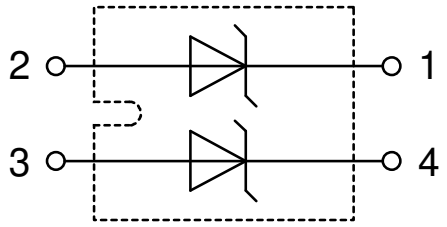
Outlines SOT-227B (minibloc)



Dim.	Millimeter		Inches	
	min	max	min	max
A	31.50	31.88	1.240	1.255
B	7.80	8.20	0.307	0.323
C	4.09	4.29	0.161	0.169
D	4.09	4.29	0.161	0.169
E	4.09	4.29	0.161	0.169
F	14.91	15.11	0.587	0.595
G	30.12	30.30	1.186	1.193
H	37.80	38.23	1.488	1.505
J	11.68	12.22	0.460	0.481
K	8.92	9.60	0.351	0.378
L	0.74	0.84	0.029	0.033
M	12.50	13.10	0.492	0.516
N	25.15	25.42	0.990	1.001
O	1.95	2.13	0.077	0.084
P	4.95	6.20	0.195	0.244
Q	26.54	26.90	1.045	1.059
R	3.94	4.42	0.155	0.167
S	4.55	4.85	0.179	0.191
T	24.59	25.25	0.968	0.994
U	-0.05	0.10	-0.002	0.004
V	3.20	5.50	0.126	0.217
W	19.81	21.08	0.780	0.830
Z	2.50	2.70	0.098	0.106



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Schottky

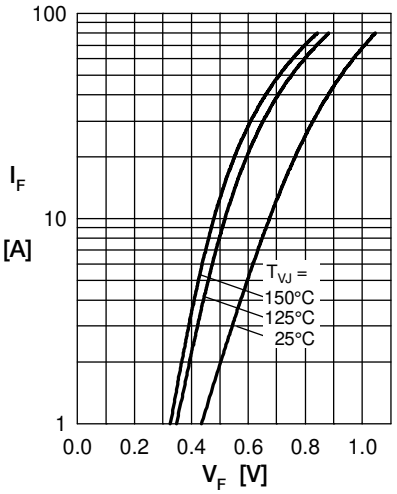

Fig. 1 Max. forward voltage drop characteristics

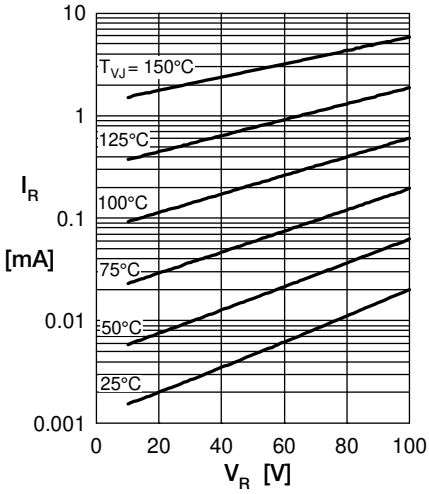

Fig. 2 Typ. reverse current I_R vs. reverse voltage V_R

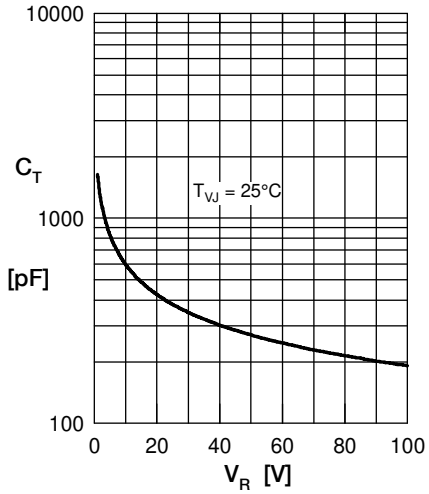

Fig. 3 Typ. junction capacitance C_T vs. reverse voltage V_R

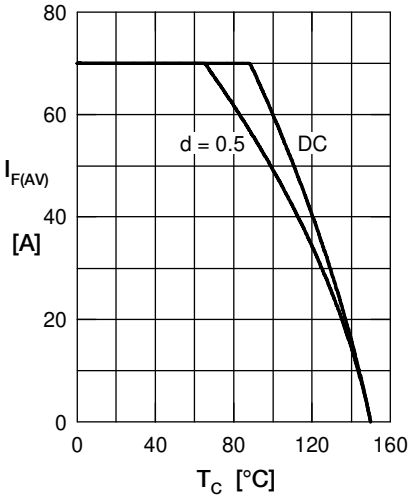

Fig. 4 Average forward current $I_{F(AV)}$ vs. case temp. T_C

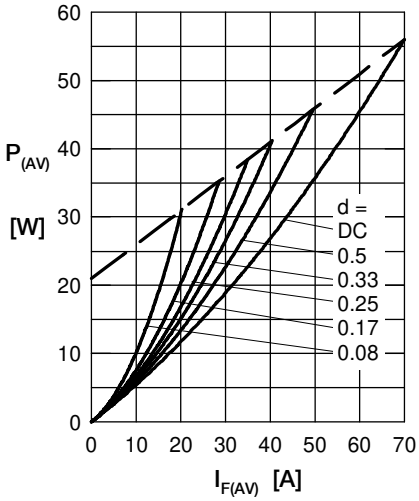

Fig. 5 Forward power loss characteristics

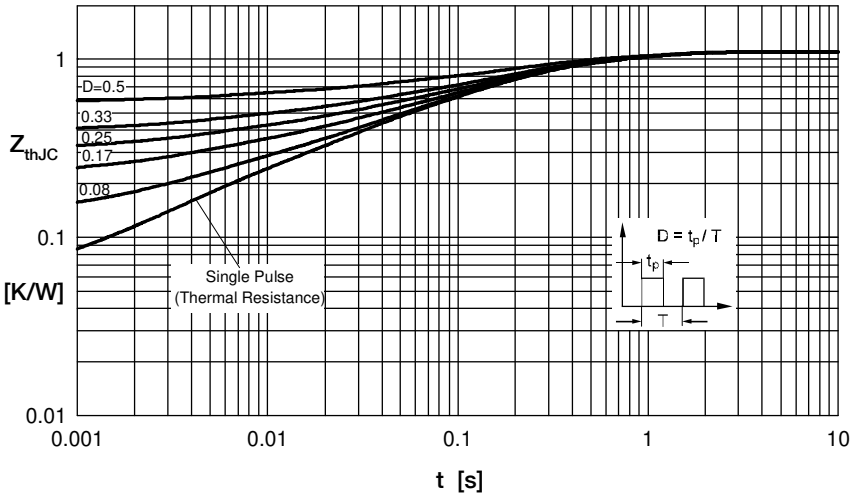

Fig. 6 Transient thermal impedance junction to case at various duty cycles

Note: All curves are per diode

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